

# **PSMN011-60MS**

N-channel 60 V 11.3 mΩ standard level MOSFET in LFPAK33

4 June 2013

Product data sheet

## 1. General description

Standard level enhancement mode N-channel MOSFET in LFPAK33 package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

#### 2. Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources
- LFPAK33 package is footprint compatible with other 3.3mm types
- Qualified to 175 °C

## 3. Applications

- AC-to-DC converters
- Synchronous rectification
- DC-DC converters

#### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	60	V
I <sub>D</sub>	drain current	T <sub>mb</sub> = 25 °C; V <sub>GS</sub> = 10 V; <u>Fig. 1</u>		-	-	61	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	-	91	W
T <sub>j</sub>	junction temperature			-55	-	175	°C
Static charact	eristics						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; T_j = 25 \text{ °C};$ Fig. 12		-	9.6	11.3	mΩ
Dynamic characteristics							
$Q_{GD}$	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 15 \text{ A}; V_{DS} = 30 \text{ V};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 14}}; \underline{\text{Fig. 15}}$		-	5.8	-	nC



## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D I
2	S	source		
3	S	source		G (S)
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

## 6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN011-60MS	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210		

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN011-60MS	M11S60

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C	-	60	V
$V_{GS}$	gate-source voltage		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	61	Α
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 1</u>	-	43	Α
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 ^{\circ}C$ ; Fig. 4	-	244	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	91	W
T <sub>stg</sub>	storage temperature		-55	175	°C
T <sub>j</sub>	junction temperature		-55	175	°C

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Symbol	Parameter	Conditions		Min	Max	Unit
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-dra	in diode					_
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	70	Α
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	244	Α
Avalanche	ruggedness	'	'	'	'	
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	$V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; $I_D$ = 61 A; $V_{sup} \le$ 60 V; $R_{GS}$ = 50 Ω; unclamped; Fig. 3		-	48.1	mJ

#### [1] Continuous current is limited by package

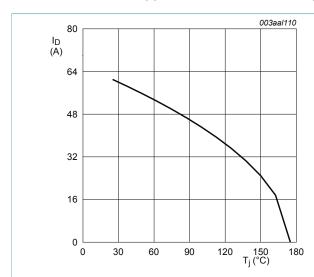


Fig. 1. Continuous drain current as a function of mounting base temperature

 $V_{GS} \ge 10 V$ 

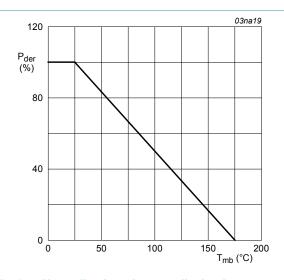


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

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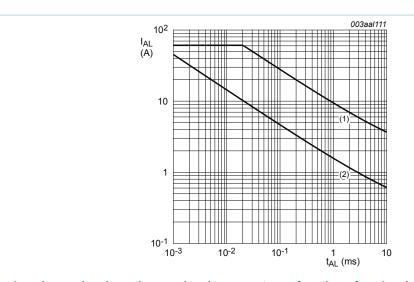
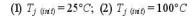


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time



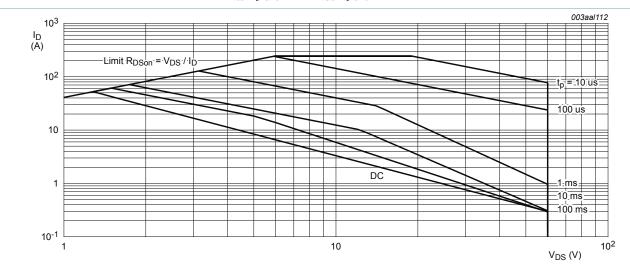


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25$ °C;  $I_{DM}$  is a single pulse

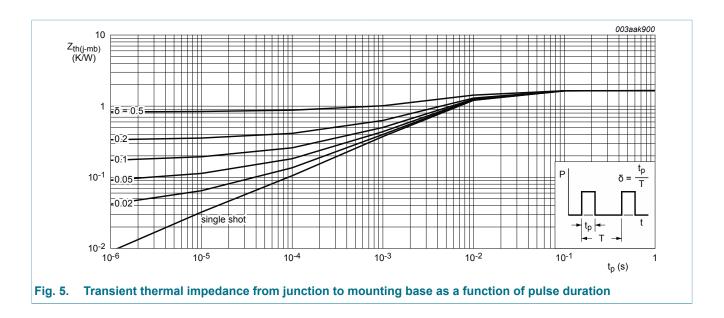
### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	1.44	1.65	K/W

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## 10. Characteristics

Table 7. Characteristics

Parameter	Conditions		Min	Тур	Max	Unit
acteristics						
drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 ^{\circ}C$		60	-	-	V
breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$		54	-	-	V
gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 10		1	-	-	V
gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C; Fig. 10; Fig. 11		2.3	3	4	V
	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = -55 °C; Fig. 10		-	-	4.6	V
drain leakage current	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	0.054	1	μA
	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C		-	-	500	μA
gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	-	100	nA
	$V_{GS}$ = -20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C		-	-	100	nA
drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 25 °C; Fig. 12		-	9.6	11.3	mΩ
	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 15 A; T <sub>j</sub> = 175 °C; Fig. 13		-	-	24.4	mΩ
gate resistance	f = 1 MHz		-	2.75	-	Ω
naracteristics		1		1		
total gate charge	I <sub>D</sub> = 15 A; V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 10 V; T <sub>i</sub> = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>		-	23	-	nC
	drain-source breakdown voltage  gate-source threshold voltage gate-source threshold voltage  drain leakage current  gate leakage current  drain-source on-state resistance  gate resistance	drain-source breakdown voltage	drain-source breakdown voltage			

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q <sub>GS</sub>	gate-source charge	I <sub>D</sub> = 15 A; V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 10 V;	-	6.1	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge	T <sub>j</sub> = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	3.9	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	2.2	-	nC
$Q_{GD}$	gate-drain charge		-	5.8	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; Fig. 16$	-	1368	-	pF
C <sub>oss</sub>	output capacitance		-	191	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	108	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 30 V; R <sub>L</sub> = 2 Ω; V <sub>GS</sub> = 10 V;	-	6.7	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	8.46	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	16.9	-	ns
t <sub>f</sub>	fall time		-	9.18	-	ns
Source-drai	in diode		l l			
$V_{SD}$	source-drain voltage	$I_S = 15 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$	-	0.84	1.2	V
t <sub>rr</sub>	reverse recovery time	$I_S = 15 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	21.7	-	ns
Q <sub>r</sub>	recovered charge	$V_{DS} = 30 \text{ V}; T_j = 25 \text{ °C}$	-	19.2	-	nC

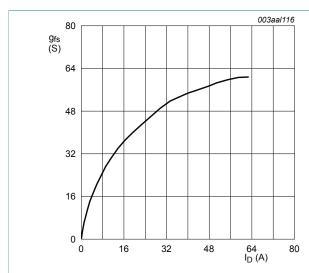


Fig. 6. Forward transconductance as a function of drain current; typical values

$$T_j = 25$$
°C;  $V_{DS} = 10V$ 

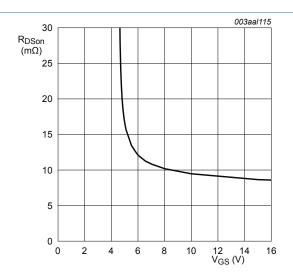


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25$$
°C;  $I_D = 15A$ 

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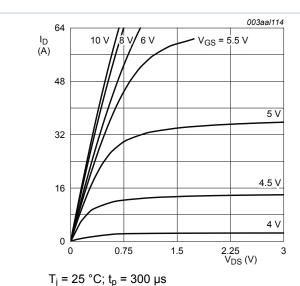


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

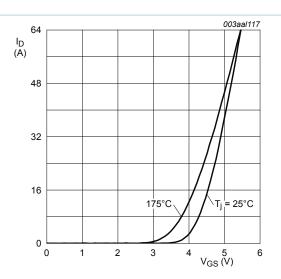


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

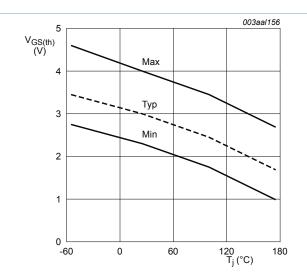


Fig. 10. Gate-source threshold voltage as a function of junction temperature

 $I_D = 1 \text{ mA}; \ V_{DS} = V_{GS}$ 

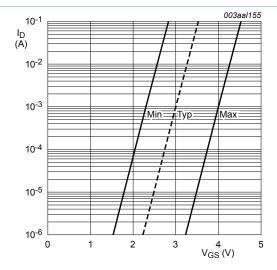
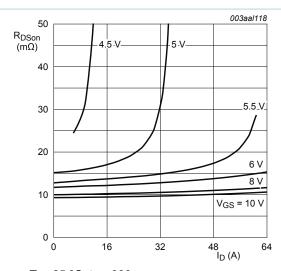


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25$$
°C;  $V_{DS} = 5V$ 

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 $T_i = 25 \,^{\circ}\text{C}; t_p = 300 \,\mu\text{s}$ 

Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

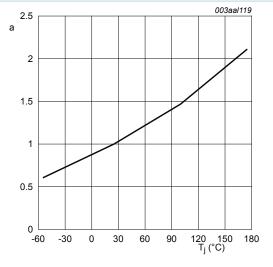


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon (25^{\circ}C)}}$$

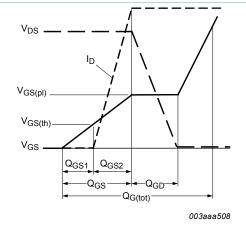


Fig. 14. Gate charge waveform definitions

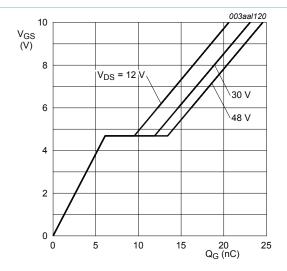


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25$$
°C;  $I_D = 15A$ 

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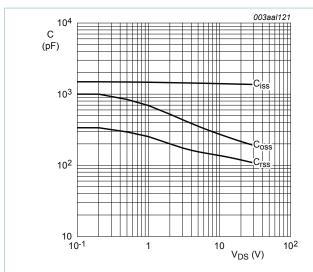
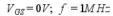
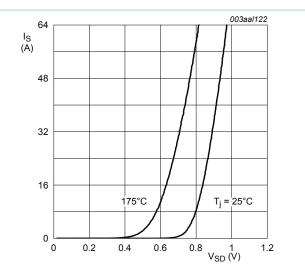


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source current as a function of source-drain as a function of drain-source voltage; typical values

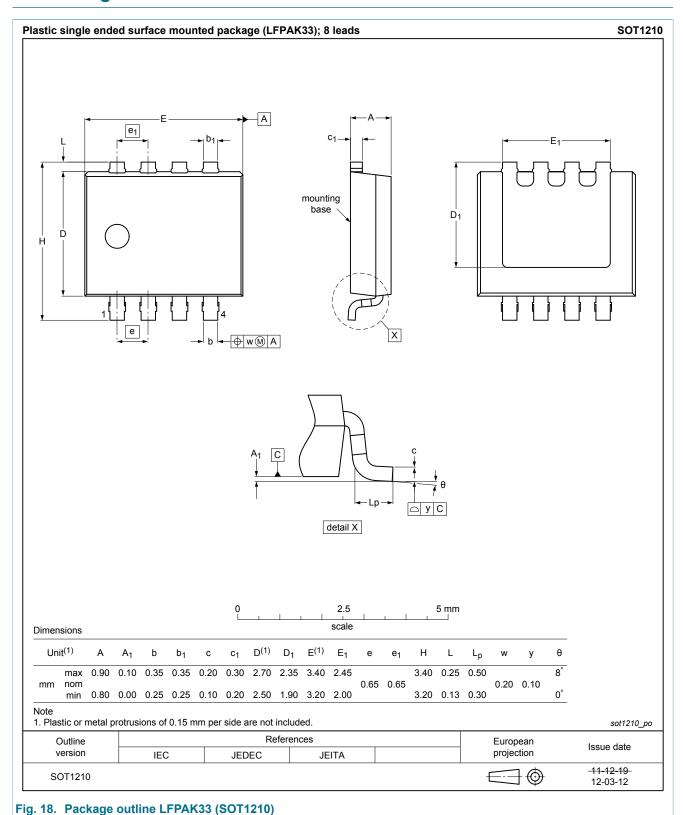




voltage; typical values

$$V_{GS} = 0V$$

## 11. Package outline



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